Terahertz Radiation from Magnetic Excitations in Diluted Magnetic Semiconductors

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Spin-based sources of THz electromagnetic radiation have recently attracted a great deal of attention, especially since spin waves were proposed to provide radiating sources to transmit or modify logical spin-based information[1]. In this context, direct light emission or absorption from the spin degrees of freedom are at the frontier of novel physics[2]. Until now, however, optically[3–5] or magnetically[6] excited spin waves have been primarily investigated in antiferromagnets such as NiO. It is less obvious to expect similar THz emission from spin excitations in semiconductors, since typical semiconductors are paramagnetic and are limited by much lower concentrations of available spins (by a factor of 10^{-4}), which results in much weaker emitted fields. Even worse, conventional semiconductors are lacking an optical spin mode with a frequency in the THz range. On the other hand, however, semiconductors - and particularly the engineering of nanostructures with high material quality - offer an excellent laboratory for controlling and studying the coupling of photon modes with the spin degrees of freedom, and thus for making advances in the spin-based THz emission.

Here we provide first steps in the experimental and theoretical exploration of spin-based THz emission from diluted magnetic semiconductors (DMSs)[7, 8] quantum wells. In DMSs, the number of available spins is controlled by the concentration x of magnetic ions (e.g. Mn) incorporated into the nonmagnetic host, so as to form crystals as Ga_{1−x}Mn_xAs or Cd_{1−x}Mn_xTe. Moreover, spin excitations occur in the form of mixed modes, in which spins of the free band carriers and those of localized magnetic ions oscillate coherently, in phase (acoustic modes) or out of phase (optical modes)[9, 10]. The precession frequency of these optical modes, typically follows the spin-split (Zeeman) energy of the carriers, Z, which is enhanced by the large exchange interaction with the d-shell electrons of the localized Mn ions. Thus the precession frequency can be adjusted in the THz range both by x and by the DMS exchange integral N_0\beta (for holes) or N_0\alpha (for electrons).

THz transient emission from Ga_{1−x}Mn_xAs in the ferromagnetic state has already been detected by the time domain measurements[11]. However, the spin origin of the radiation was not demonstrated, as the frequency range of the observed transient did not match neither the acoustic nor optical modes frequencies. We preferentially used a well controlled test-bed DMS system made of a two dimensional electron gas (2DEG) embedded in a Cd_{1−x}Mn_xTe quantum well (QW), which has been introduced [12–15] as an alternative for magnetic excitations study in DMS. In this paramagnetic system the acoustic and optical spin wave modes have been evidenced by Raman spectroscopy [12–15] and time-domain optical pump-probe experiments[16, 17]. Upon application of an external magnetic field B_{z} parallel to the quantum well plane (see inset of Fig.1 and Ref.[18]), each paramagnetic Mn atom supports a thermal average spin ⟨I_z(B,T)⟩. The spin-split Zeeman energy Z of the QW conduction band, writes:

\[ Z(B,T) = \bar{\varepsilon}N_0\alpha\langle I_z(B,T)\rangle - |g_e|\mu_B B, \tag{1} \]

In Eq.(1), N_0\alpha = −0.22 eV [19], \bar{\varepsilon} is the effective Mn concentration (for low x, \bar{\varepsilon} ≈ x), and g_e = −1.64 is the electron Landé factor in CdMnTe (\mu_B > 0).

In our experiment, the spin-polarized 2DEGs reside in each of 20 QWs within a Cd_{1−x}Mn_xTe multi quantum-well structure[18]. The sample exhibit well resolved quantum Hall plateaus and Shubnikov de Haas oscillations. 2DEG sheet densities n_{2D} and mobilities were found to be 5 × 10^{11} cm^{-2} and 2.4 × 10^{4} cm^{2}/Vs. The Mn concentration, as determined from Raman measurements[14], is x = 1.75%, which implies that Z

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can be as high as 6.7 meV ($\sim$ 1.6 THz) for $B = 8$ T. In this case the 2DEG becomes highly spin polarized with a spin polarization degree $\zeta = (n_i - n_{\perp})/(n_i + n_{\perp}) \sim -Z/2E_F \sim 40\%$ ($E_F$ is the Fermi energy). A circularly polarized near-infrared femtosecond pulse propagating perpendicularly to the quantum well plane (see inset of Fig.1 and Ref.[18]) exchanges angular momentum with the electron spins and the Mn spins through a Raman generation process thanks to strong spin-orbit interaction in the valence states[20, 21]. A collective spin precession starts and within the relaxation time, the spin oscillation radiates an electromagnetic field which is probed by electro-optic sampling. In Fig.1(a), we have plotted for various static magnetic fields, the transient electric field radiated from the sample excited by an optical pulse centered at 763 nm. The electro-optic sampling detection was set to be sensitive to the electric field component parallel to the static magnetic field axis ($z$ axis). A transient, well resolved, oscillation of the emitted field is observed. The amplitude of the electric field oscillation saturates with the external magnetic field as expected (see Fig.1(b) and text below). The emission was measured with an energy per pulse $E_P \simeq 70$ nJ/cm$^2$, which is orders of magnitude smaller than that used for Ga$_{1-x}$Mn$_x$As in Ref.[11] (400 $\mu$J/cm$^2$) or for NiO in Ref.[22] (20 mJ/cm$^2$). The power requirements in this work are strongly reduced by the strong spin-orbit interaction occurring in valence states and the sharpness of the optical resonance involved in the Raman generation mechanism. The latter is assured by the recent progress of MBE growth of II-VI semiconductor heterostructures[23].

Illustration of the resonance is given in Fig.2(a), where, for a fixed magnetic field, we tuned the central wavelength $\lambda_0$ of the optical pulse across the lowest 2DEG’s optical resonance positioned at 763 nm (as determined by cw optical measurements). The amplitude of the radiated oscillation is maximum at 763 nm. This is a first evidence that the emission originates from 2DEG electrons and not from the CdTe buffer or from the GaAs substrate.

The spin origin of the radiation is inferred from Fig.2(c) where the Fourier-transform of the detected field transient (shown in Fig.1(a)) is plotted for circularly and linearly polarized optical pulses in the presence or absence of the magnetic field. As clearly seen the radiation is detected only when the magnetic field is switched on and when the optical pulse is circularly polarized. This reflects perfectly the symmetry of the inverse Faraday effect [25–27] in a cubic crystal: a circularly polarized pulse exchange a transient magnetic moment along the propagation direction while a linearly polarized pulse has no magnetic effect, but couples to charge excitations only[20]. In addition, in absence of external magnetic field, the out of phase spin wave disappears. These observations also demonstrate that the detected radiation cannot be related to a magnetic field enhancement of a radiation originating from charge excitations as described in Ref.[24]. Indeed, the pulse, normally incident and focused on 1mm diameter spot, can induce a charge motion only perpendicular to the quantum well plane and the Lorentz force is unable to induce a dipole along the magnetic field axis ($z$ axis), which is the detected radiation polarization.

We confirm the spin origin by providing a quantitative treatment of the amplitude of the radiation and the frequencies present in the generated THz transient, and demonstrate that it supports the data. The impulsive optical electromagnetic field, circularly polarized in the plane ($x$, $z$) of the sample couples to the crystal through the Hamiltonian: $\hat{H}(t) = -\mathbf{e} \mathbf{A}(t) \cdot \hat{\mathbf{p}}/m^* = \int E_x(t) e^{i\omega t} d\omega$, where $\mathbf{A}(t)$ is the time dependent vector potential. Before the pulse excites the sample, the crystal is in its equilibrium state $|i\rangle$ where electron and Mn spins are anti-parallel to the magnetic field. The macroscopic Mn spin $\hat{\mathbf{M}} = \sum_j \hat{\mathbf{I}}_j$, has the equilibrium value $\langle i | \hat{\mathbf{M}}_z | i \rangle = M_{z_i} = x N_0 \langle L_z(B,T) \rangle wL^2$, where $w$ is the illuminated QW surface. The macroscopic Mn spin $\hat{\mathbf{M}} = \sum_j \hat{\mathbf{I}}_j$, has the equilibrium value $\langle i | \hat{\mathbf{M}}_z | i \rangle = M_{z_i} = x N_0 \langle L_z(B,T) \rangle wL^2$, where $w$ is the QW thickness. After its action, through the Raman process, the pulse leaves the system in the state [18, 21]:

$$|\Psi(t)\rangle = c_i e^{-i\omega t} |i\rangle + \sum_m c_m e^{-i\omega_m t} |m\rangle$$

(2)
FIG. 2. (Color online). (a) Transient electric field amplitude as a function of central wavelength of the pulse. The pulse energy was 136 nJ/cm². (b) Variation of the detected radiated amplitude (squares) with the pulse energy and comparison with the calculations carried to 1st-order with Eqs.(3)-(4) and to all orders[18]. (c) Fourier amplitudes of the electric field when excited by circularly (top line) and linearly (middle line) polarized pulse at B=8 T. Two peaks are seen at 0.5 THz (v_l) and 2.4 THz (v_2) when the pulse is circularly polarized. The bottom line is the result of circular excitation at B=0 T. All data in (c) were taken with 82 nJ/cm² energy pulses.

where |m⟩ are excited quantum states with eigen pulsation ω_m and c_m writes (to lowest order in the field [18]):

\[ c_m = \frac{i \pi}{\hbar^2} \int \sum_n \frac{\langle m | H_{\omega - \omega_m} | n \rangle \langle n | H^*_{\omega + i\eta_n} | i \rangle}{\omega_m - \omega + i\eta_n} \, d\omega \]  (3)

In Eq.(3), |n⟩ are intermediate states, η_n is their decay rate and ω_{m} = ω_{m} - ω over a range given typically by η_n. A coherence between |i⟩ and a spin-wave state |f⟩ will be driven, if the pulse spectrum contains two photons separated by ω_f, and if these two photons can together transfer magnetic momentum. For the latter, the spin-mixture in the hole state involved in the interband electron-hole pair intermediate state |n⟩ is essential[18, 20, 21]. The cubic symmetry of the CdTe crystal makes the Raman process obeys the general symmetry of the inverse Faraday effect[26, 27]. It results[18] that cf = i \int \chi_f (\omega) (f | \tilde{\bf S} \cdot \tilde{\bf A}_{\omega - \omega_f} \times \tilde{\bf A}_y^* | i \rangle \, d\omega, where \chi_f (ω) is a scalar. Therefore, the circularly polarized pulse couples to the spin degrees of freedom as an effective magnetic field proportional to \tilde{\bf A}_{\omega - \omega_f} \times \tilde{\bf A}_y, which is, vanishing for a linearly polarized pulse, but directed along the propagation direction y for a circular pulse. Thus, our circular pulse induces an out of equilibrium magnetization and leaves the system in a state such that the average Mn and electron spins are respectively M(t = 0) = (0, M_{y0}, M_{z0}) and S(t = 0) = (0, S_{y0}, S_{z0}) (M(t) = ⟨Ψ(t)|\hat{\bf M}|Ψ(t)⟩). Both macroscopic spins will further experience a spontaneous precession with a relaxation towards their equilibrium states.

In a semi-classical picture, the spin magnetization is associated to a surface current density carried by each quantum well: i_s = e_{\mu B}B(t) × y/uL², where S(t) = ⟨Ψ(t)|\hat{\bf S}|Ψ(t)⟩. Continuity relations of the electromagnetic field at the QW interface leads to the radiated field from each QW after transmission in the air:

\[ e_{R}(t) = \frac{2\pi \mu_0}{1 + n \, uL^2} g_{\mu B} B(t) \]  (4)

where n is the refraction index of the substrate. Therefore, the radiated field is polarized parallel to the z-axis, consistent with the experimental observations. Its instantaneous value is proportional to the transverse component S_y(t), and its amplitude proportional to the number of spins, thus, to the spin-polarization degree ζ that saturates with B as the Zeeman energy of Eq.(1) does. As shown in Fig.1(b), the measured amplitude of the radiated field reproduces this behavior. The transverse component of the spin is induced by the optical pulse. Consequently, the radiated amplitude is maximum for a
pulse energy for which the spins are totally tilted out of their equilibrium axis. Fig.2(b) shows the trend of a saturation of the emitted amplitude when the energy per pulse is further increased from $\approx80$ nJ/cm$^2$. Thus, the emitted amplitude naturally departs from the calculations of Eqs.(3)-(4) valid to lowest order in the optical field. A better agreement in the high energy regime has been obtained when going beyond this approximation by resolving the intra-pulse spin dynamics to all orders[18].

A similar non-linear behavior has been found in Ref.[28].

The frequency analysis shown in Fig.2(d) reveals two main frequencies $\nu_1$ and $\nu_2$. The two frequencies present in the transients are extracted by a linear prediction algorithm[18] and plotted in Fig.3(a). The fitted signal is superposed in Fig.1(a). In Fig.3(a), the two frequencies $\nu_1$ and $\nu_2$ are compared with the precession frequency of the optical spin mode determined by Raman spectroscopy (blue dots) [14]. The latter matches $Z(B,T)/h$ (blue curve) where $Z$ is given in Eq.(1). However, although both $\nu_1$ and $\nu_2$ frequencies exhibit a similar magnetic field dependence they are not directly associated with $Z(B,T)/h$ and appear as two frequencies almost symmetrically split from $Z(B,T)/h$.

The transient at $B=8$ T shows that the probed spin component $S_z(t)$ experiences quick changes of its phase. This strongly suggests that its precession axis evolves in time. The phenomenon is similar to a magnetic resonance, where a magnetic field $B_0$ oscillates transversally to the polarizing magnetic field $B_Z$. Here, the oscillating field is the strong exchange field of the Mn spins which acts as a torque $\alpha S \times M$. $M(t)$ precesses around the $z$ axis at $\omega_{Mn} = \mu_B B / h$ (see lowest green line in Fig.3(a)), since we can neglect the action of the exchange field from the electrons[18]. Due to the transverse oscillation of the electrons[18], the Mn ions. The time dependent coupling between the Mn spins and the transverse component of the electron spin $S_x(t)$ has a motion composed of three sinusoids at pulsations $\omega_{Mn}$ and $\Omega \pm \omega_{Mn}$. The corresponding three frequencies are plotted in Fig.3(a) (green dashed and purple dotted and dashed curves). $\Omega + \omega_{Mn}$ matches $\nu_2$ within 10% when setting $M_{\|} = 0$, i.e. when assuming that the Mn spins have been tilted totally out of the plane after the pulse. However, $\nu_1$ does not match $\Omega - \omega_{Mn}$.

In order to understand the discrepancy concerning $\nu_1$, we solved numerically the set of coupled equations of motion for $S(t)$ and $M(t)$ (see Ref.[18] for details):

$$\frac{dS}{dt} = g_s \mu_B B S \times z + \tilde{\alpha} S \times M - \frac{\alpha_c}{|S_z|} S \times \frac{dS}{dt}$$

where $\tilde{\alpha}$ and $\alpha_c$ is a Gilbert damping parameter. $M(t)$ is driven by a similar equation[18]. The time evolution of $S(t)$ and spin trajectories are plotted in Fig.3(b) and Fig.3(c) respectively. To account for the fast electron spin relaxation rate (3 ps), $\alpha_c$ was set to 0.07, while for the slower Mn relaxation, we used $\alpha_{Mn} = 0.01$. From Fig.3(c), we see that the electron spins try to precess around the oscillating $M(t)$ axis. The damping relaxes its components transverse to the oscillating axis, hence after 3 ps, $S(t)$ follows $M(t)$.

A detailed frequency analysis of the simulated $S_z(t)$ results in three characteristic frequencies. The highest frequency ($\nu_2$ num., solid red curve in Fig.3(a)) is in very good agreement with $\Omega + \omega_{Mn}$ and hence, $\nu_2$: the lowest frequency corresponds to $\omega_{Mn}$ and the intermediate one ($\nu_1$ num., solid orange curve) is close to $\nu_1$ as shown in Fig.3(a). The $\omega_{Mn}$ pulsation is not seen in the transient of Fig.2(a) because the detection process of the THz field acts as a sharp high pass-filter with cut-off frequency around 0.3 THz. To account for this, we have filtered the simulated $S_z(t)$ with a numerical high-pass filter[18]. The filtered trajectory of $S_z(t)$ is plotted in Fig.3(b). The filtering has a negligible effect on $\nu_2$ num., but slightly shifts $\nu_1$ num. to lower values ($\nu_1$ filtered, solid light orange curve), increasing its agreement with $\nu_1$. To summarize, the identification of frequencies observed in the transient is supported by the theory within a 10% quantitative agreement, when taking into consideration the non-linear coupled spin dynamics between the electrons and the Mn ions. The time dependent coupling between these two systems splits the observed frequencies from $Z/h$. This mechanism explains in addition the difference with the Raman determination of the precession modes. Raman probes spin fluctuations, therefore the Mn spins are negligibly disturbed such that $M_{\|} \approx 0$, electrons are sensitive to a static exchange magnetic field aligned with the $z$ axis.

In conclusion, we have measured THz transient fields radiated from optically generated spin-wave excitations in DMS multiple quantum wells. The radiation is polarized parallel to the static magnetic field axis and appears only with a circular polarized pulse. Thus, it’s origin cannot be attributed to charge excitations. The spin-wave origin of the emitted field is supported by first-principles theoretical analysis of all aspects of the experiment, including, the generation mechanism, spin dynamics and the properties of emitted radiation. Hence, we provide evidences that DMS quantum wells constitute a highly promising test-bed for deeper investigations in the basic issues of spin-based THz emission, like for instance, addressing the intrinsic spin precession decay caused by the radiation[29] or manipulating the coupling between spin and radiation at the quantum level, e.g., by inserting such DMS quantum wells into cavities[30, 31].

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[18] See Supplemental Material at [URL...] for details on the sample structure, the THz setup, the intermediate calculations of equations present in the text.
Samples

The sample is a multi-quantum well (QW) with 20 QWs. The sample has a periodic Cd$_{1-x}$Mn$_x$Te/CdMgTe design grown by molecular beam epitaxy on a (100) GaAs substrate. The period includes: a 20 nm thick Cd$_{1-x}$Mn$_x$Te QW, a 20 nm thick Cd$_{0.8}$Mg$_{0.2}$Te spacer, a 5 nm- thickness iodine donors layer and a 50 nm thick Cd$_{0.8}$Mg$_{0.2}$Te barrier. 2DEG originates from electrons tunneling from the I doping layer to the QW.

THz measurements

Consider the impulsive electromagnetic field, centered at the wavelength $\lambda_0$ $(\omega_0 = 2\pi c/\lambda_0)$, circularly polarized in the plane $(x, z)$ of the sample: $E(t) = Re \left[ (x + iz) \frac{E_P}{\pi c \epsilon_0 \omega_0} e^{i\omega_0 t} \int \tilde{e}_\omega e^{i\omega t} d\omega \right]$, where $\tilde{e}_\omega$ is the dimensionless normalized Fourier transform of the field $\int \frac{\lambda_0}{2\pi} \int | \tilde{e}(\omega) |^2 d\omega = 1$ and $E_P$ is the pulse energy per surface unit. The electromagnetic field couples to the crystal through the Hamiltonian: $H(t) = -eA(t) \cdot \hat{p}/m^*$. Before the pulse hits the sample $(t = -\infty)$, the crystal is in its equilibrium state $|i\rangle$. During the pulse action the system is in the state:

$$|\Psi(t)\rangle = c_i(t)e^{-i\omega_it}|i\rangle + \sum_m c_m(t)e^{-i\omega_mt}|m\rangle$$  \hspace{1cm} (1)

where $|m\rangle$ are excited quantum states. We aim at finding $c_f(t)$ where $|f\rangle$ is the spin wave state. For that, we write the equation of motion, project it, eliminate the $c_i(t)$ for $m \neq i, f$ and find the set of coupled equations:

$$c_i(t) = 1 - \frac{1}{\hbar^2} \sum_{n = -\infty}^{\infty} \int_{-\infty}^{\infty} \int_{-\infty}^{\infty} \langle i| \hat{H}(t') |n\rangle \langle n| \hat{H}(t'') |i\rangle c_i(t'') e^{-i\omega_{ni}t'} e^{-i\omega_{nj}t''} dt'dt''$$

$$- \frac{1}{\hbar^2} \sum_{n = -\infty}^{\infty} \int_{-\infty}^{\infty} \int_{-\infty}^{\infty} \langle i| \hat{H}(t') |n\rangle \langle n| \hat{H}(t'') |f\rangle c_f(t'') e^{-i\omega_{ni}t'} e^{-i\omega_{jf}t''} dt'dt''$$
$$c_f(t) = -\frac{1}{\hbar^2} \sum_{n,-\infty} \int_{t'}^{t} \langle f | \hat{H}(t') | n \rangle \langle n | \hat{H}(t') | i \rangle c_i(t') e^{-i\omega_n t} e^{-i\omega_n t'} dt dt'$$

$$-\frac{1}{\hbar^2} \sum_{n,-\infty} \int_{t'}^{t} \langle f | \hat{H}(t') | n \rangle \langle n | \hat{H}(t') | f \rangle c_f(t') e^{-i\omega_n t} e^{-i\omega_n t'} dt dt'$$

(2)

where $|n\rangle$ are intermediate states involving a hole in the valence band (in contrast to $|i\rangle$ and $|f\rangle$ which have no holes).

Solving these equations yields the dynamics of the state during the pulse and the exact final state after the pulse action. In the manuscript we used a 1st order approximation which consists of solving the system analytically by keeping only terms to lowest order in the field:

$$c_i = 1$$

$$c_f = i \frac{\pi}{\hbar^2} \sum_n \frac{\langle f | \hat{H}_{\omega - \omega_f} | n \rangle \langle n | \hat{H}_{\omega} | i \rangle}{\omega_i - \omega + i\eta_n} dw$$

(3)

where, $\hat{H}_{\omega}$ is the Fourier transform of $\hat{H}(t) = \int \hat{H}_\omega e^{i\omega t} dt$ and $\eta_n$ is the decay rate of the intermediate state $|n\rangle$. The results of this approximation are also compared with a full treatment of (2) which has been solved numerically. However, in the full treatment was achieved by neglecting the spin-conserving terms like $\langle f | H(t') | n \rangle \langle n | H(t') | f \rangle$.

In the following, we detail the calculation of the radiated field in the 1st order approximation.

An efficient Raman generation of a spin-wave quantum state $|f\rangle$ will occur if: (a) $\omega_f < \Delta \omega$, where $\Delta \omega$ is the pulse spectral bandwidth; (b) the central pulse pulsation is resonant with the intermediate optical transition of the crystal $\omega_n$; (c) the decay rate $\eta_n$ of the intermediate state is low and (d) the two-photon process $\langle f | \hat{H}_{\omega - \omega_f} | n \rangle \langle n | \hat{H}_{\omega} | i \rangle$ can transfer spin momentum from the state $|i\rangle$ to the state $|f\rangle$.

As we will see below, the latter is permitted thanks to the resonance with an intermediate state that contains a spin-orbit orbit, $k$ is the in-plane momentum and $\sigma = \uparrow, \downarrow$ labels the spin. $|\beta\rangle$ is a valence-band state that due to the quantum well confinement is a combination of light and heavy-hole states. The light-hole states in Zinc-Blende semiconductors possess the spin-mixture to obtain the inverse Faraday effect. The latter write: $|\beta\rangle = \alpha_{\pm 1/2} |J = \frac{3}{2}, J_z = \pm \frac{1}{2}\rangle = \alpha_{\pm 1/2} \left[-\sqrt{\frac{3}{4}} (X \pm \gamma) \mp \sqrt{\frac{3}{4}} (X \mp \gamma) \mp \gamma \right]$. $|X\rangle$ is a $\pi$-orbital in the $x$ direction. Thus, a $z$-polarized photon couples an electron $|S\rangle$ with $|J = \frac{3}{2}, J_z = \frac{1}{2}\rangle$ and a $x$-polarized photon couples the same state with an electron $|S\rangle$. Owing to this selection rule, spin-momentum transfer is forbidden for a linearly polarized pulse, but allowed to a circularly polarized pulse with both polarizations $X$ and $Z$ present. In addition, the resonance occurs when $\omega$ is close to the electron-hole pair transition: $\omega_{\alpha} - \omega_{\beta} \simeq \omega_{e-th}$. Given the approximation that the denominator in Eq.(4) does not depend on $\alpha$ and $\beta$ anymore, and using the form of the electron and hole states, we obtain:

$$c_f = \int \frac{i 2\pi \left| \langle S | \hat{p}_z | X \rangle \right|^2}{3h^2 \omega_{e-th} - \omega + i\eta_{e-th}} \frac{\langle f | A_{\omega-\omega_f} \cdot \hat{S} | i \rangle}{\chi_f(\omega)} d\omega$$

where $|\langle S | \hat{p}_z | \alpha \rangle|^2/m^* \simeq 88eV$, is the Kane momentum for CdTe, identical for $\alpha = X, Y, Z$. The above form is consistent with the inverse Faraday effect in cubic crystals[5]. Using the form of the circular field given above, we further obtain:

$$c_f = i \langle f | \hat{S}_y | i \rangle \frac{\lambda_0 \times e^2 \times E_P}{12\pi \times \varepsilon_0 m^* c^2 \times h \omega_0^2} \frac{|\langle S | \hat{p}_z | X \rangle|^2}{m^*} I(\lambda_0)$$

with

$$I(\lambda_0) = \int \frac{\tilde{\varepsilon}_{\omega-\omega_f} \tilde{\varepsilon}_\omega}{\omega_{e-th} - \omega - i\eta_{e-th}} d\omega$$

It makes appear the electron classical radius $e^2/\varepsilon_0 m^* c^2 \simeq 0.34pm$. We now inject $c_f$ into Eq.(1) and keep only linear terms in $c_f$ to obtain:

$$\langle \hat{S}_x(t) \rangle = n_{2D} L^2 \xi \frac{\lambda_0 \times e^2 \times E_P}{24\pi \times \varepsilon_0 m^* c^2 \times h \omega_0^2} \frac{|\langle S | \hat{p}_z | X \rangle|^2}{m^*} \times \left| I(\lambda_0) \right| \cos(\omega_f t - \varphi_0)$$

we have used $\langle f | \hat{S}_y | i \rangle \langle i | \hat{S}_z | f \rangle = -i n_{2D} L^2 \xi /4$ and $I(\lambda_0) = |I(\lambda_0)| e^{i\varphi_0}$.

From this, using Eq.(4) of the manuscript, we get the amplitude of the radiated field:

$$|e_R| = \frac{\eta_0 g_{e-B} n_{2D}}{1 + n_X} \frac{\lambda_0 \times 0.34pm \times 88eV \times \hat{E}_P}{12\pi \times \omega_0^2} \frac{|I(\lambda_0)|}{\left| I(\lambda_0) \right|}$$

where $\hat{E}_P$ takes into account the transmission coefficient of the Air/CdTe Interface and also the $\alpha_{\pm 1/2}$ factor:

$$\hat{E}_P = E_P \times t_{Air/CdTe}^2 \times |\alpha_{1/2}|^2$$
Spin dynamics equations and simulations

The Hamiltonian of the 2DEG and Mn spins embedded in the Cd$_{1-x}$Mn$_x$Te QW writes:

$$
\hat{H} = \hat{H}_{\text{Kin}} + \hat{H}_{\text{Coulomb}} + \hat{H}_{\text{Zeeman}} \\
\hat{H}_{\text{Zeeman}} = g_e\mu_B\hat{S} \cdot \mathbf{B} + g_{\text{Mn}}\mu_B\hat{M} \cdot \mathbf{B}
$$

where $\alpha$ is the exchange coupling between conduction electrons and Mn atoms for electrons and Mn respectively. In the equilibrium state at temperature $T$, the random phase approximation is used to make the $\otimes$ and $\otimes$ approximations for the electron and Mn macroscopic spin operators, respectively (see Ref.[7] for further details). Then, we take the quantum average spins $S$ and $M$ for the electron and Mn macroscopic spin operators, respectively ($\overline{\langle S \rangle}$ and $\overline{\langle M \rangle}$) accounting for the relaxation.

$$
\langle S \rangle = \langle \hat{S} \rangle \quad \text{and} \quad \langle M \rangle = \langle \hat{M} \rangle
$$

where $\langle \hat{S} \rangle$ and $\langle \hat{M} \rangle$ are the 3D electron spin density in a splitted coordinates frame $\mathbf{r} = (r//, y)$ with $r//$, the in-plane position and $y$ the out of plane coordinate. $\chi(y)$ is the electron envelope-function of the first subband of the QW. The $i$ index accounts for the $i$-th electron of the 2DEG, its spin $1/2$ is described by the operator $i_\uparrow$ and its position is $r_/i$. $\hat{M}(\mathbf{r}) = \sum_j \hat{I}_j \delta(\mathbf{r} - \mathbf{r}_j)$ is the Mn 3D spin density. The $j$-th $3/2$-spin $\hat{I}_j$ of a single Mn impurities is localized on the cation site $\mathbf{R}_j$. $\hat{S} = \iint \hat{S}(\mathbf{r}) d^3r = \sum_i i_\uparrow$ and $\hat{M} = \iint \hat{M}(\mathbf{r}) d^3r = \sum_j \hat{I}_j$ are the macroscopic spin operators for electrons and Mn respectively. In the equilibrium state at temperature $T$, each Mn spin assumes the average value $\langle I_j \rangle (B, T)$, which is the thermodynamic average over the five occupied states of the Mn atom d-shell, given by the modified Brillouin function[6]. The 2DEG has the equilibrium spin polarization $\zeta = (n_\uparrow - n_\downarrow)/n_{2D}$.

From the above Hamiltonian, we derive dynamical equations for the electron and Mn macroscopic spin operators, respectively (see Ref.[7] for further details). Then, we take the quantum average spins $S$ and $M$ and make the random phase approximation $\langle \hat{S} \times \hat{M} \rangle$ to obtain the following dynamical equations:

$$
\hbar \frac{d\hat{S}}{dt} = |g_e| \mu_B B \hat{S} \times \mathbf{z} + \hbar \alpha_e \hat{S} \times M - \frac{\hbar \alpha_e}{|S_{zi}|} \hat{S} \times \frac{d\hat{S}}{dt} \\
\hbar \frac{d\hat{M}}{dt} = -g_{\text{Mn}}\mu_B B \hat{M} \times \mathbf{z} - \hbar \alpha_{\text{Mn}} \hat{M} \times M - \frac{\hbar \alpha_{\text{Mn}}}{|M_{zi}|} \hat{M} \times \frac{d\hat{M}}{dt}
$$

where $\alpha = \alpha_e/\omega L^2/\hbar$. We have introduced Gilbert damping terms ($\alpha_e$ and $\alpha_{\text{Mn}}$) accounting for the relaxation. $S_{zi} < 0$ and $M_{zi} < 0$ are the equilibrium macroscopic spins of, respectively, electrons and Mns.

The numerical solution of the above coupled equations was carried with the normalized quantities: $S = -S_{zi} \hat{S}$ and $M = -M_{zi} \hat{M}$. The dynamical equations for these normalized quantities are:

$$
\hbar \frac{d\hat{S}}{dt} = |g_e| \mu_B B \hat{S} \times \mathbf{z} + \Delta \hat{S} \times \hat{M} - \hbar \alpha_e \hat{S} \times \frac{d\hat{S}}{dt} \\
\hbar \frac{d\hat{M}}{dt} = -g_{\text{Mn}}\mu_B B \hat{M} \times \mathbf{z} - K \hat{S} \times \hat{M} - \hbar \alpha_{\text{Mn}} \hat{M} \times \frac{d\hat{M}}{dt}
$$

Where $\Delta = -\hbar \alpha M_{zi}$ is the Overhauser shift of the electron spins and $K = -\hbar \alpha S_{zi}$ is the Knight shift of Mn spins. The former is typically in the meV range, while the latter is in the $\mu$eV range. This justifies the derivation of Eq.(5), where we considered the Mn spins as acting on the electrons as an independent exchange field oscillating at $\omega_{Mn}$.

**Frequencies analysis**

To analyze the frequencies in the experimental transient, we used a backward linear prediction algorithm detailed in Ref.[8]. This algorithm yields, the frequencies, amplitudes, decay rates and phases of sinusoids present in the transient.

The frequency analysis of the simulated curves presented in Fig.3(b) was also carried with the same algorithm.

To account for the detection filtering, the simulated curves, when indicated, were numerically filtered by a Kaiser high-pass filter.

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